

# SI2321DS-T1-GE3

#### SI2321DS-T1-GE3 Information

| D                  | <br>SI2321DS-T1-GE3<br>Vishay Siliconix<br>Discrete Semiconductor Products<br>Transistors - FETs, MOSFETs - Single<br>MOSFET P-CH 20V 2.9A SOT-23<br>TO-236-3, SC-59, SOT-23-3<br>For the pricing/inventory/lead time, please contact<br>us |                 |
|--------------------|---|-----------------|
| For Reference Only | Website: https://www.heisener.com<br>E-mail: salesdept@heisener.com   | Request a Quote |

### **Certified Quality**

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



## SI2321DS-T1-GE3 Specifications

| Manufacturer Part Number               | SI2321DS-T1-GE3                      |
|--|--------------------------------------|
| Manufacturer                           | Vishay Siliconix                     |
| Category                               | Discrete Semiconductor Products      |
|  | Transistors - FETs, MOSFETs - Single |
| Package                                | TO-236-3, SC-59, SOT-23-3            |
| Series                                 | TrenchFET?                           |
| FET Type                               | P-Channel                            |
| Technology                             | MOSFET (Metal Oxide)                 |
| Drain to Source Voltage (Vdss)         | 20V                                  |
| Current - Continuous Drain (Id) @ 25°C | 2.9A (Ta)                            |
| Drive Voltage (Max Rds On, Min Rds On) | 1.8V, 4.5V                           |
| Vgs(th) (Max) @ Id                     | 900mV @ 250µA                        |
| Gate Charge (Qg) (Max) @ Vgs           | 13nC @ 4.5V                          |
| Input Capacitance (Ciss) (Max) @ Vds   | 715pF @ 6V                           |
| Vgs (Max)                              | $\pm 8V$                             |
| FET Feature                            | -                                    |
| Power Dissipation (Max)                | 710mW (Ta)                           |
| Rds On (Max) @ Id, Vgs                 | 57 mOhm @ 3.3A, 4.5V                 |
| Operating Temperature                  | -55°C ~ 150°C (TJ)                   |
| Mounting Type                          | Surface Mount                        |
| Supplier Device Package                | SOT-23-3 (TO-236)                    |
| Package / Case                         | TO-236-3, SC-59, SOT-23-3            |
|  | Report errors?                       |

#### SI2321DS-T1-GE3 Guarantees



**Quality Guarantees** 

We provide 90 days warranty. \* If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

# SERVICE BUARANTEE

#### **Service Guarantees**

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

#### SI2321DS-T1-GE3 Payment Methods



#### SI2321DS-T1-GE3 Shipping Methods



If you have any question about SI2321DS-T1-GE3, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com